

SGF23N60UF

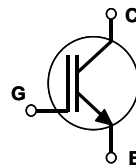
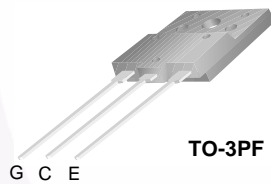
600 V PT IGBT

General Description

Fairchild's UF series IGBTs provide low conduction and switching losses. UF series is designed for the applications such as general inverters where High Speed Switching is required feature.

Features

- 12 A, 600 V, $T_C = 100^\circ\text{C}$
- Low Saturation Voltage: $V_{CE(sat)} = 2.1\text{ V @ } I_C = 12\text{ A}$
- Typical Fall Time.220ns at $T_J = 125^\circ\text{C}$
- High Speed Switching
- High Input Impedance



Application

- General Inverter, PFC

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Description | SGF23N60UF | Unit | |
|-------------|---|-----------------------------|-------------|------------------|
| V_{CES} | Collector-Emitter Voltage | 600 | V | |
| V_{GES} | Gate-Emitter Voltage | ± 20 | V | |
| I_C | Collector Current | @ $T_C = 25^\circ\text{C}$ | 23 | A |
| | Collector Current | @ $T_C = 100^\circ\text{C}$ | 12 | A |
| $I_{CM(1)}$ | Pulsed Collector Current | | 92 | A |
| P_D | Maximum Power Dissipation | @ $T_C = 25^\circ\text{C}$ | 75 | W |
| | Maximum Power Dissipation | @ $T_C = 100^\circ\text{C}$ | 30 | W |
| T_J | Operating Junction Temperature | | -55 to +150 | $^\circ\text{C}$ |
| T_{stg} | Storage Temperature Range | | -55 to +150 | $^\circ\text{C}$ |
| T_L | Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds | | 300 | $^\circ\text{C}$ |

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Unit |
|-----------------|---|------|------|---------------------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case | -- | 1.6 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | -- | 40 | $^\circ\text{C}/\text{W}$ |

Electrical Characteristics of IGBT $T_C = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--------|-----------|-----------------|------|------|------|------|
|--------|-----------|-----------------|------|------|------|------|

Off Characteristics

| | | | | | | |
|--------------------------------------|---|---|-----|-----|-----------|---------------------------|
| BV_{CES} | Collector-Emitter Breakdown Voltage | $V_{GE} = 0\text{ V}, I_C = 250\text{ }\mu\text{A}$ | 600 | -- | -- | V |
| $\frac{\Delta BV_{CES}}{\Delta T_J}$ | Temperature Coeff. of Breakdown Voltage | $V_{GE} = 0\text{ V}, I_C = 1\text{ mA}$ | -- | 0.6 | -- | $\text{V}/^\circ\text{C}$ |
| I_{CES} | Collector Cut-Off Current | $V_{CE} = V_{CES}, V_{GE} = 0\text{ V}$ | -- | -- | 250 | μA |
| I_{GES} | G-E Leakage Current | $V_{GE} = V_{GES}, V_{CE} = 0\text{ V}$ | -- | -- | ± 100 | nA |

On Characteristics

| | | | | | | |
|---------------|---|---|-----|-----|-----|---|
| $V_{GE(th)}$ | G-E Threshold Voltage | $I_C = 12\text{ mA}, V_{CE} = V_{GE}$ | 3.5 | 4.5 | 6.5 | V |
| $V_{CE(sat)}$ | Collector to Emitter Saturation Voltage | $I_C = 12\text{ A}, V_{GE} = 15\text{ V}$ | -- | 2.1 | 2.6 | V |
| | | $I_C = 23\text{ A}, V_{GE} = 15\text{ V}$ | -- | 2.6 | -- | V |

Dynamic Characteristics

| | | | | | | |
|-----------|------------------------------|--|----|-----|----|----|
| C_{ies} | Input Capacitance | $V_{CE} = 30\text{ V}, V_{GE} = 0\text{ V},$ $f = 1\text{ MHz}$ | -- | 720 | -- | pF |
| C_{oes} | Output Capacitance | | -- | 100 | -- | pF |
| C_{res} | Reverse Transfer Capacitance | | -- | 25 | -- | pF |

Switching Characteristics

| | | | | | | |
|--------------|-------------------------|---|----|-----|-----|---------------|
| $t_{d(on)}$ | Turn-On Delay Time | $V_{CC} = 300\text{ V}, I_C = 12\text{ A},$ $R_G = 23\text{ }\Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 25^\circ\text{C}$ | -- | 17 | -- | ns |
| t_r | Rise Time | | -- | 27 | -- | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | -- | 60 | 130 | ns |
| t_f | Fall Time | | -- | 70 | 150 | ns |
| E_{on} | Turn-On Switching Loss | | -- | 115 | -- | μJ |
| E_{off} | Turn-Off Switching Loss | | -- | 135 | -- | μJ |
| E_{ts} | Total Switching Loss | | -- | 250 | 400 | μJ |
| $t_{d(on)}$ | Turn-On Delay Time | $V_{CC} = 300\text{ V}, I_C = 12\text{ A},$ $R_G = 23\text{ }\Omega, V_{GE} = 15\text{ V},$ Inductive Load, $T_C = 125^\circ\text{C}$ | -- | 23 | -- | ns |
| t_r | Rise Time | | -- | 32 | -- | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | -- | 100 | 200 | ns |
| t_f | Fall Time | | -- | 220 | 250 | ns |
| E_{on} | Turn-On Switching Loss | | -- | 205 | -- | μJ |
| E_{off} | Turn-Off Switching Loss | | -- | 320 | -- | μJ |
| E_{ts} | Total Switching Loss | | -- | 525 | 800 | μJ |

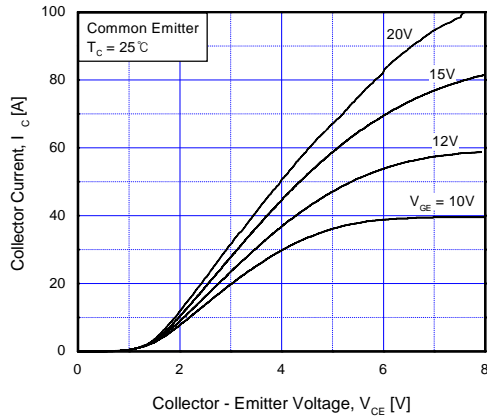


Fig 1. Typical Output Characteristics

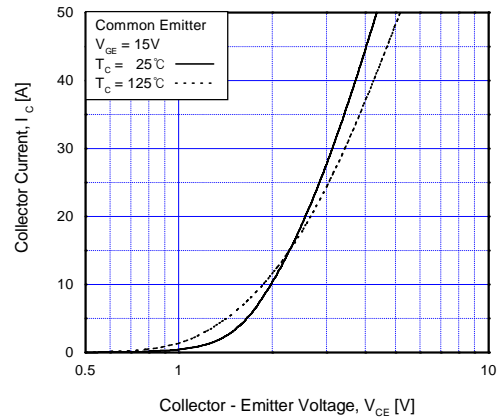


Fig 2. Typical Saturation Voltage Characteristics

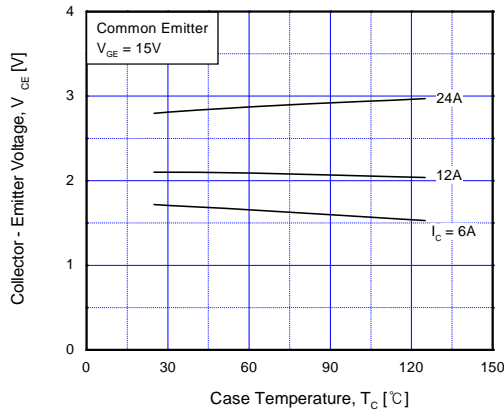


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

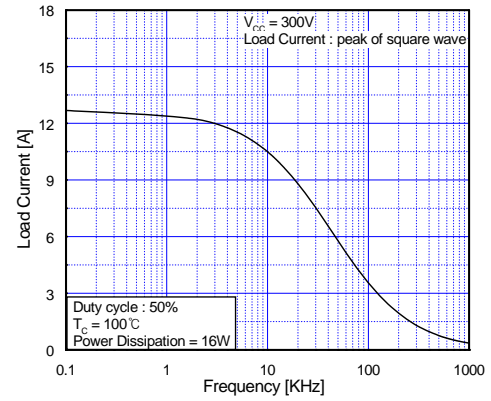


Fig 4. Load Current vs. Frequency

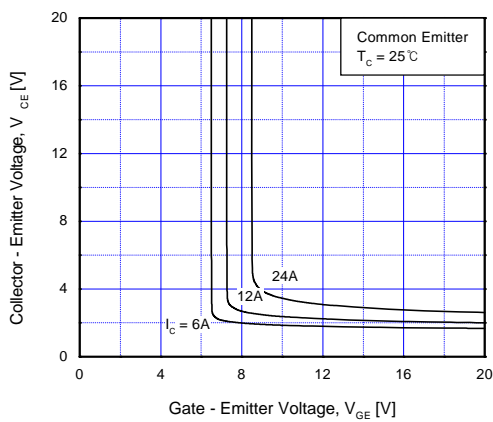


Fig 5. Saturation Voltage vs. V_{GE}

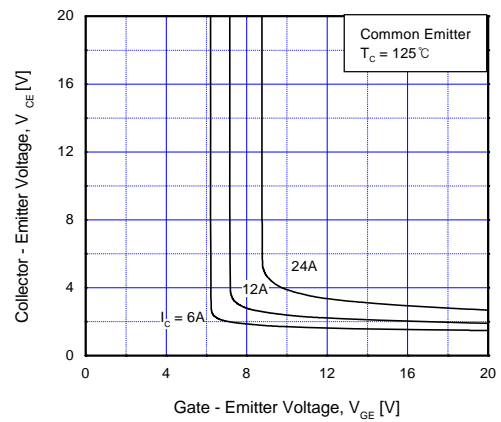


Fig 6. Saturation Voltage vs. V_{GE}

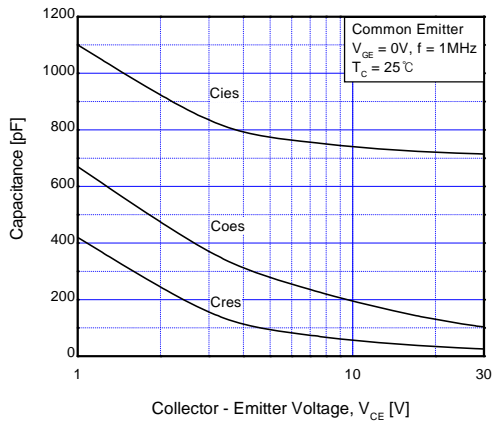


Fig 7. Capacitance Characteristics

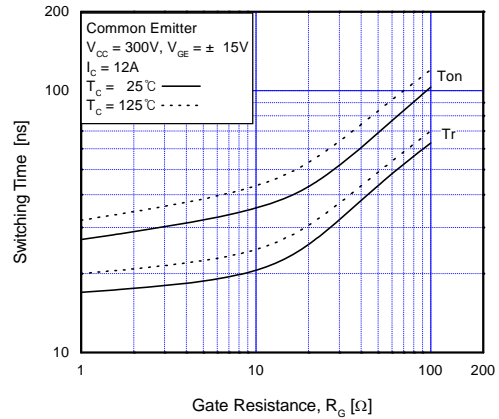


Fig 8. Turn-On Characteristics vs. Gate Resistance

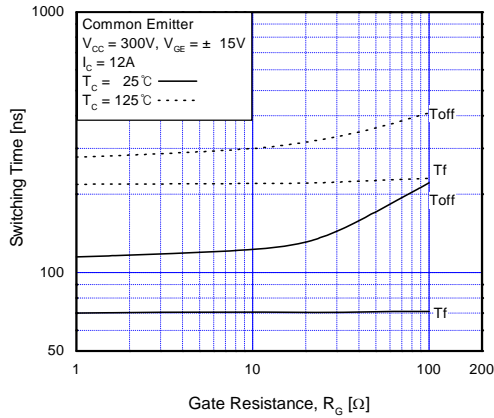


Fig 9. Turn-Off Characteristics vs. Gate Resistance

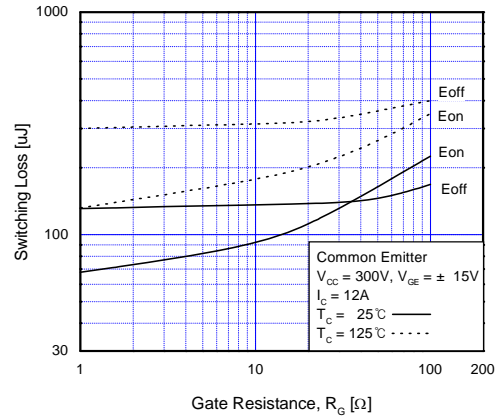


Fig 10. Switching Loss vs. Gate Resistance

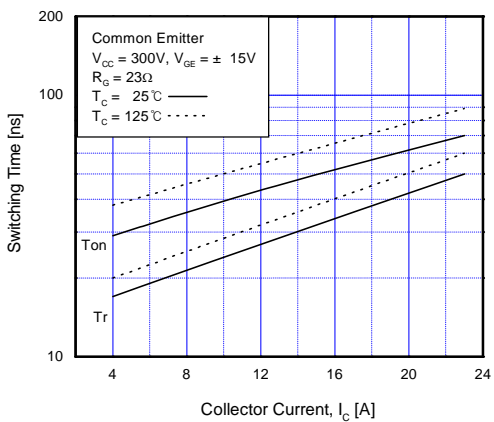


Fig 11. Turn-On Characteristics vs. Collector Current

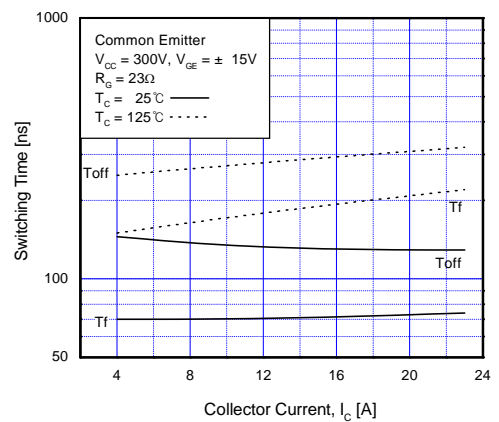


Fig 12. Turn-Off Characteristics vs. Collector Current

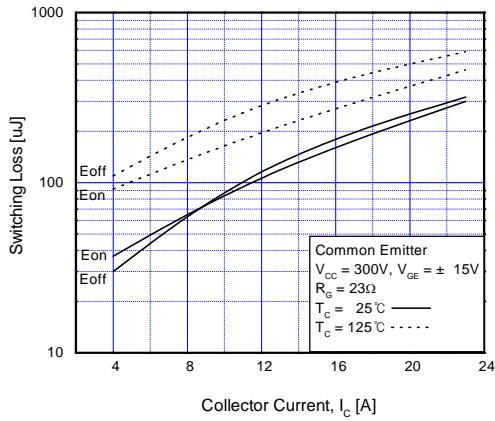


Fig 13. Switching Loss vs. Collector Current

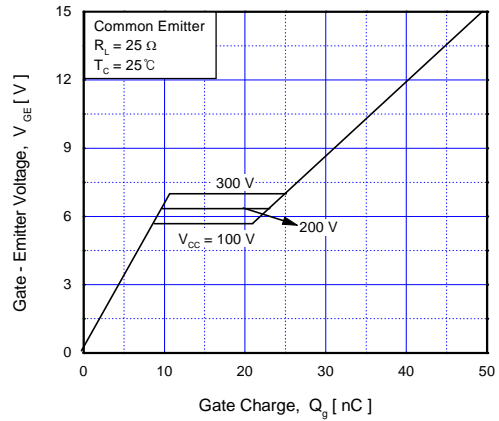


Fig 14. Gate Charge Characteristics

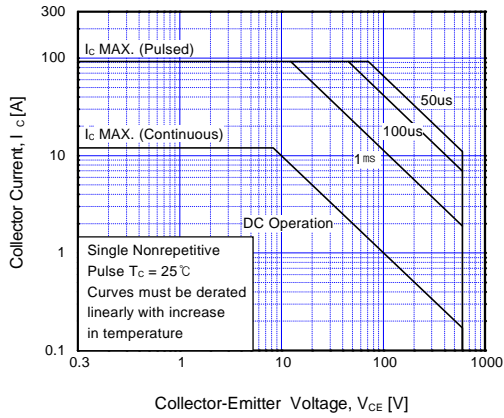


Fig 15. SOA Characteristics

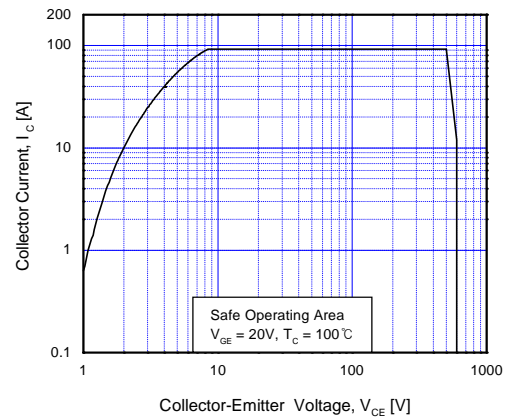


Fig 16. Turn-Off SOA Characteristics

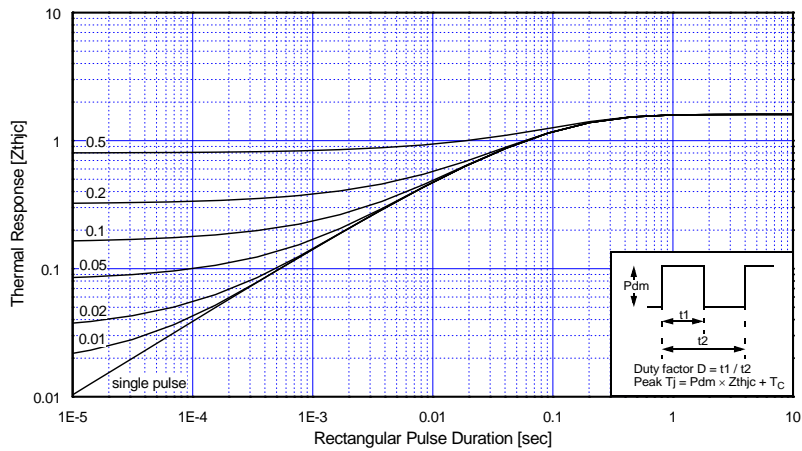
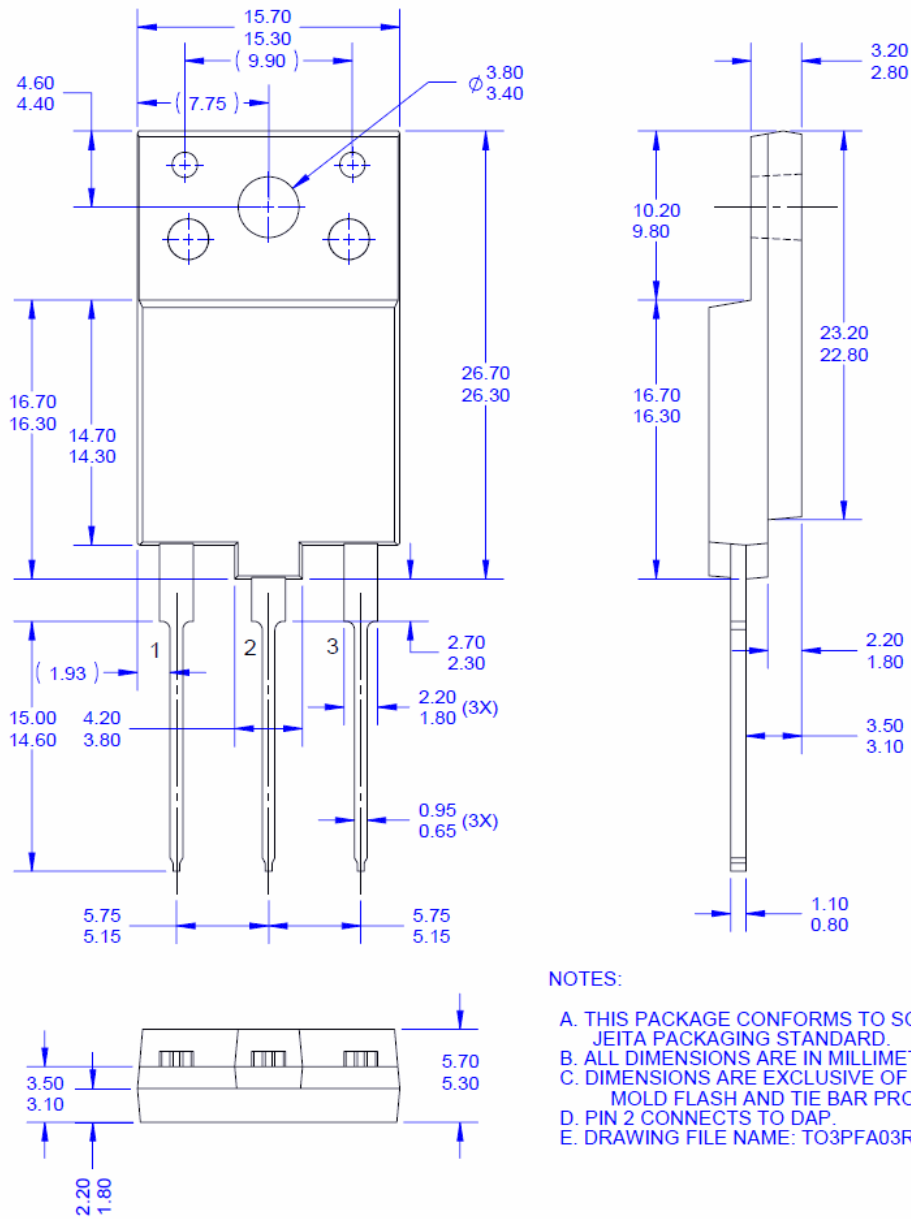


Fig 17. Transient Thermal Impedance of IGBT

Mechanical Dimensions



NOTES:

- A. THIS PACKAGE CONFORMS TO SC94 JEITA PACKAGING STANDARD.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- D. PIN 2 CONNECTS TO DAP.
- E. DRAWING FILE NAME: T03PFA03REV1

Figure 18. TO3PF, MOLDED, 3LD, FULLPACK (AG)

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| BitSiC™ | Global Power Resource SM | Programmable Active Droop™ | GENERAL |
| Build it Now™ | GreenBridge™ | QFET® | TinyBoost® |
| CorePLUS™ | Green FPS™ | QS™ | TinyBuck® |
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